MCH6344

ON Semiconductor®

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P-Channel Power MOSFET -30V, -2A, 150mΩ, Single MCPH6

Features

- ON-resistance RDS(on)1=115m Ω (typ.)
- · 4V drive
- · Halogen free compliance
- · Protection diode in

Specifications

Absolute Maximum Ratings at Ta=25°C

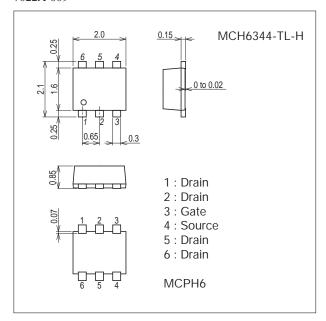
Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V _{DSS}		-30	V
Gate to Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	ID		-2	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-8	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

This product is designed to "ESD immunity < 200V*", so please take care when handling.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7022A-009



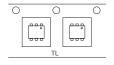
Product & Package Information

• Package : MCPH6

• JEITA, JEDEC : SC-88, SC-70-6, SOT-363

• Minimum Packing Quantity : 3,000 pcs./reel

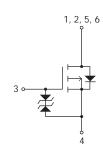
Packing Type: TL



Marking



Electrical Connection

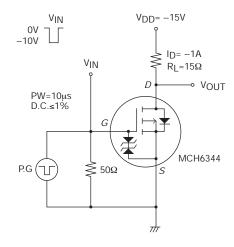


^{*} Machine Model

Electrical Characteristics at Ta=25°C

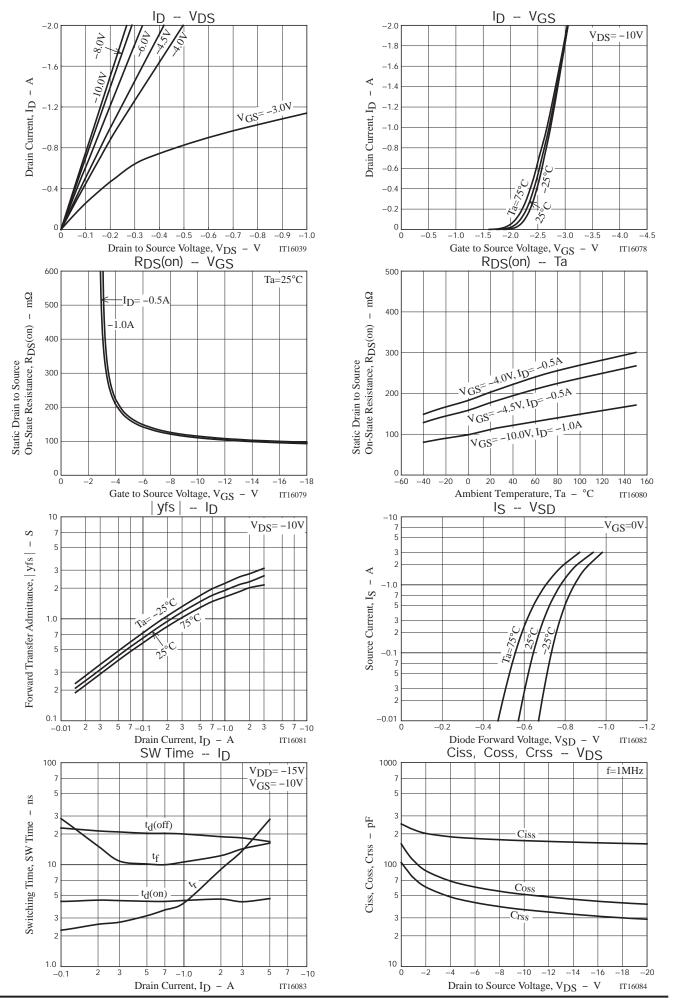
Parameter	Symbol	Conditions	Ratings			Unit
		Conditions	min	typ	max	Uniii
Drain to Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0V			-1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =-10V, I _D =-1mA -1.2			-2.6	V
Forward Transfer Admittance	yfs	V _D S=-10V, I _D =-1A		1.9		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =-1A, V _G S=-10V		115	150	mΩ
	R _{DS} (on)2	I _D =-0.5A, V _G S=-4.5V		182	255	mΩ
	R _{DS} (on)3	I _D =-0.5A, V _G S=-4V		208	292	mΩ
Input Capacitance	Ciss			172		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		51		pF
Reverse Transfer Capacitance	Crss			36		pF
Turn-ON Delay Time	t _d (on)			4.5		ns
Rise Time	t _r	Considered Took Classick		4.2		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		20		ns
Fall Time	t _f			10.6		ns
Total Gate Charge	Qg			3.9		nC
Gate to Source Charge	Qgs	V _{DS} =-15V, V _{GS} =-10V, I _D =-2A		0.6		nC
Gate to Drain "Miller" Charge	Qgd	1		0.8		nC
Diode Forward Voltage	V _{SD}	I _S =-2A, V _{GS} =0V		-0.86	-1.5	V

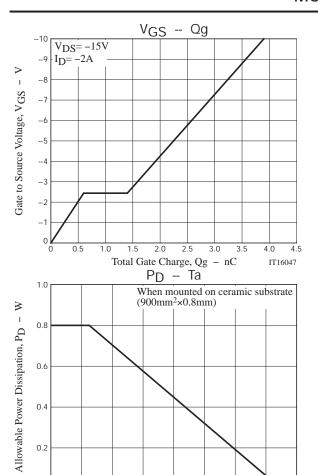
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo	
MCH6344-TL-H	MCPH6	3,000pcs./reel	Pb-Free and Halogen Free	





0 L

20

60

80

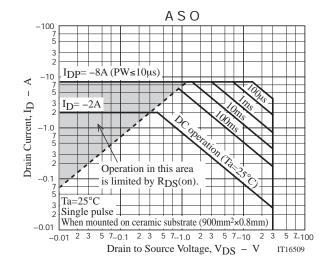
Ambient Temperature, Ta - °C

100

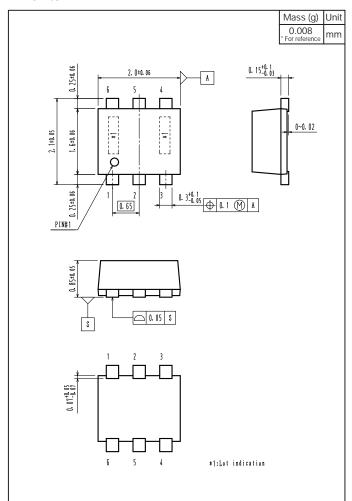
140

160

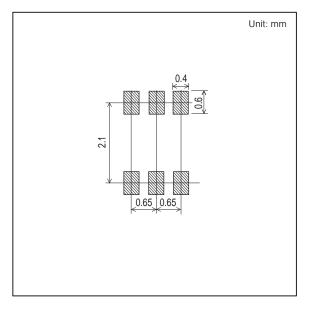
IT16510



Outline Drawing MCH6344-TL-H



Land Pattern Example



Note on usage: Since the MCH6344 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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